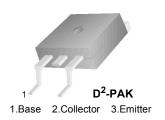
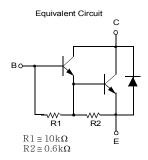


October 2008

FJB102 High Voltage Power Darlington Transistor

- High DC Current Gain : h_{FE} =1000 @ V_{CE} =4V, I_{C} =3A (Min.)
- · Low Collector-Emitter Saturation Voltage





Absolute Maximum Ratings

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	100	V
V _{CEO}	Collector-Emitter Voltage	100	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	8	Α
I _{CP}	* Collector Current (Pulse)	15	Α
I _B	Base Current (DC)	1	Α
P_{C}	Collector Dissipation (T _C = 25°C)	80	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-65 ~ 150	°C

^{*} Pulse Test: PW = $300\mu s$, Duty Cycle = 2% Pulsed

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Max.	Units
BV _{CEO(sus)}	Collector-Emitter Sustaining Voltage	I _C = 30mA, I _B = 0	100		V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 500\mu A, I_C = 0$	10		V
I _{CBO}	Collector Cut-off Current	V _{CB} = 100V, I _E = 0		50	μΑ
I _{CEO}	Collector Cut-off Current	$V_{CE} = 50V, I_{E} = 0$		50	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$		2	mA
h _{FE}	DC Current Gain	V _{CE} = 4V, I _C = 3A V _{CE} = 4V, I _C = 8A	1000 200	20000	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 3A, I _B = 6mA		2.0	V
		I _C = 8A, I _B = 80mA		2.5	V
V _{BE(ON)}	Base-Emitter Saturation Voltage	V _{CE} = 4V, I _C = 8A		2.8	V
C _{ob}	Output Capatitance	V _E = 10V, I _E = 0, f = 1MHz		200	pF

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Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FJB102	FJB102	D ² -PAK	-		

Typical Performance Characteristics

Figure 1. Static Characterstic

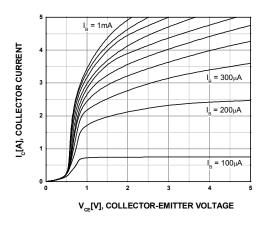


Figure 2. DC Current Gain

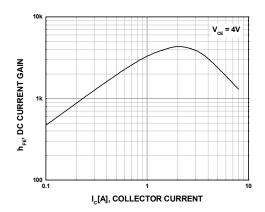


Figure 3. Saturation Voltage

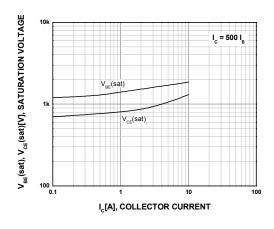


Figure 4. Collector Output Capacitance

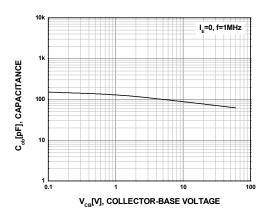


Figure 5. Forward Biased Safe Operating Area

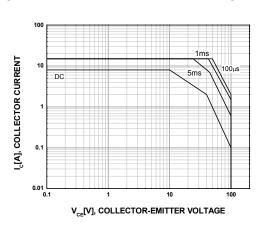
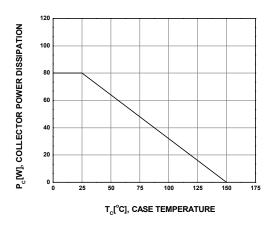


Figure 6. Power Derating

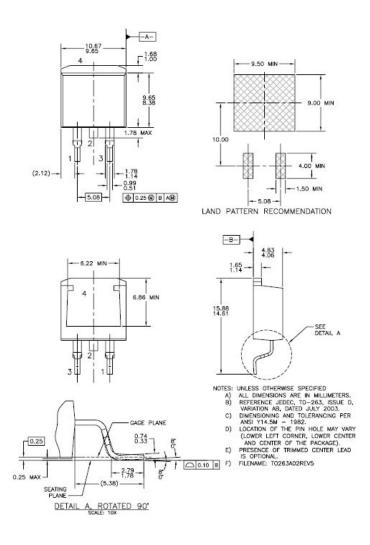


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Mechanical Dimensions

D2-PAK



Dimensions in Millimeters





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